

## **KSD1943**

### **High Power Transistor**



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	8	V
Ic	Collector Current	3	А
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	40	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 25 \text{mA}, I_B = 0$	60		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 80V, I_{E} = 0$		100	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 8V, I_{C} = 0$		10	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 4V, I_{C} = 0.5A$	400	2000	
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.05A$		1.5	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.05A$		1	V

# **Typical Characteristics**

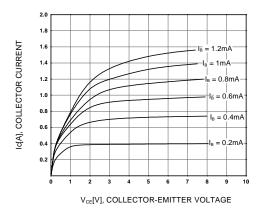


Figure 1. Static Characteristic

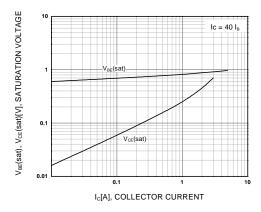


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

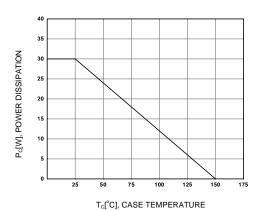


Figure 5. Power Derating

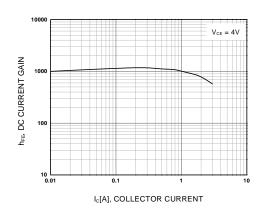


Figure 2. DC current Gain

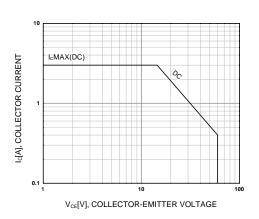
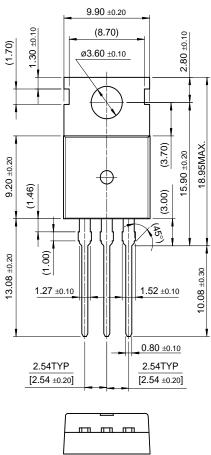


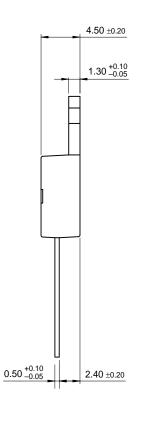
Figure 4. Safe Operating Area

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# **Package Demensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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